

ARIMA OPTOELECTRONICS CORP. Report No. : CE/2005/C4270A

7 TH FL, NO. 349, JEN HO RD., SEC. 2, DASH, TAOYUAN, Date : 2005/12/22

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### The following merchandise was (were) submitted and identified by the client as:

<u>Type of Product</u>: APC LASER DIODE

Sample Received : 2005/12/15

<u>Testing Date</u> : 2005/12/15 TO 2005/12/22

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**Test Result** : - Please see the next page -

Daniel Yeh, M.R. Operation Manager Signed for and on behalf of

SGS TAIWAN LTD.



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#### **Test Result**

PART NAME NO.1 : MIXED ALL PARTS

Test Item (s):	Unit	Method	MDL	Result
				No.1
Monobromobiphenyl	%	With reference to USEPA3540C or	0.0005	N.D.
Dibromobiphenyl	%		0.0005	N.D.
Tribromobiphenyl	%		0.0005	N.D.
Tetrabromobiphenyl	%		0.0005	N.D.
Pentabromobiphenyl	%		0.0005	N.D.
Hexabromobiphenyl	%	USEPA3550C. Analysis was	0.0005	N.D.
Heptabromobiphenyl	%	performed by HPLC/DAD, LC/MS or GC/MS. (prohibited by 2002/95/EC (RoHS), 83/264/EEC, and	0.0005	N.D.
Octabromobiphenyl	%		0.0005	N.D.
Nonabromobiphenyl	%		0.0005	N.D.
Decabromobiphenyl	%	76/769/EEC)	0.0005	N.D.
Total PBBs	%	1	-	N.D.
(Polybrominated				
biphenyls)/Sum of above				
Monobromobiphenyl ether	%	With reference to USEPA3540C or USEPA3550C. Analysis was performed by HPLC/DAD, LC/MS or GC/MS. (prohibited by 2002/95/EC (RoHS), 83/264/EEC, and 76/769/EEC)	0.0005	N.D.
Dibromobiphenyl ether	%		0.0005	N.D.
Tribromobiphenyl ether	%		0.0005	N.D.
Tetrabromobiphenyl ether	%		0.0005	N.D.
Pentabromobiphenyl ether	%		0.0005	N.D.
Hexabromobiphenyl ether	%		0.0005	N.D.
Heptabromobiphenyl ether	%		0.0005	N.D.
Octabromobiphenyl ether	%		0.0005	N.D.
Nonabromobiphenyl ether	%		0.0005	N.D.
Decabromobiphenyl ether	%		0.0005	N.D.
Total PBBEs(PBDEs)	%		-	N.D.
(Polybrominated biphenyl				
ethers)/Sum of above				
Total of Mono to Nona-	%		-	N.D.
brominated biphenyl				
ether. (Note 4)				



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Test Item (s):	Unit	Method	MDL	Result
				No.1
Chromium VI (Cr+6)	ppm	UV-VIS after reference to US EPA 3060A.	2	N.D.
Cadmium (Cd)	ppm	ICP-AES after reference to EN 1122, method B:2001 or other acid digestion.	2	N.D.
Mercury (Hg)	ppm	ICP-AES after reference to US EPA 3052 or other acid digestion.	2	N.D.
Lead (Pb)	ppm	ICP-AES after reference to US EPA 3050B or other acid digestion.	2	6237.0

NOTE: (1) N.D. = Not detected (<MDL)

- (2) ppm = mg/kg
- (3) MDL = Method Detection Limit
- (4) Decabromodiphenyl ether (DecaBDE) in polymeric applications is exempted by Commission Decision of 13 Oct 2005 amending Directive 2002/95/EC notified under document 2005/717/EC.
- (5) PBBEs=PBDEs=Polybrominated Diphenyl Ethers=PBDOs=PBBOs.
- (6) " " = Not Regulation



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